Set: 01

#### **BRAC** University

Semster: Spring 2020

Course No: CSE251

Course Title: ELECTRONIC DEVICES AND CIRCUITS

Section: 11

Faculty: ABA



Midterm Full Marks: 40

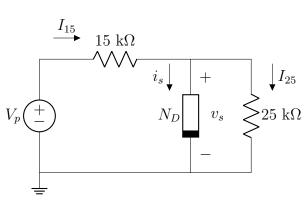
TIme: 2 hours

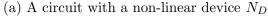
Date: March 10, 2022

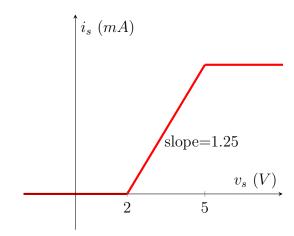
Answer all 4 questions. All the questions carry equal marks.

# Question 1 [CO1]

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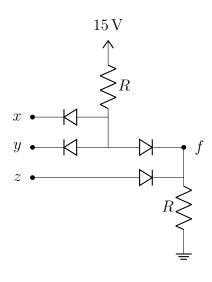


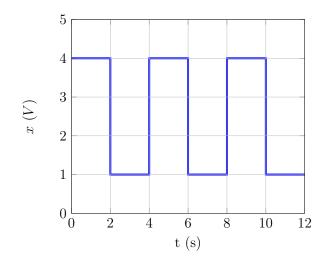
(b) IV Characteristics of the non-linear device  $N_D$ 

- (a) **Identify** the equivalent linear circuit models for the 3 linear segments in the IV characteristics of the non-linear device  $N_D$  and **calculate** the model parameters. [3]
- (b) Show the alternative representation of the circuit in Figure (a). [2]
- (c) **Detect** the operating region for the device when  $v_s = 3 \text{ V}$  and **calculate** the current through the device,  $i_s$ , for this voltage. [2]
- (d) Apply KVL and KCL to calculate the value of voltage source  $V_p$  when  $v_s = 3$  V. [3]

# Question 2 [CO2]

10





For this question, all of the diodes are ideal.

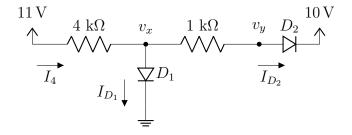
- (a) Assuming x, y, z are boolean variables, **analyze** the circuit on the left to find an expression of f in terms of x, y, and z.
- (b) Analyze the circuit on the left again to find the waveform (voltage vs time graph) of f assuming x, y, z are voltage signals, where y = 2 V, z = 3 V, and x has a waveform as shown in the figure on the right = [5]
- (c) **Design** a circuit using ideal diodes to implement the logic function f = x.y.z. Here "." denotes logical AND. [2]

**Bonus: Design** a circuit using ideal diodes to implement the XOR logic function between x and y, assuming you have access to x,  $\bar{x}$ , y, and  $\bar{y}$ .

#### Question 3 [CO1]

10

- (a) **Analyze** the following circuit to find the values of  $I_{D_1}$ ,  $I_{D_2}$ ,  $v_x$ , and  $v_y$ . Here, **use** the Method of Assumed State using the CVD model of diode with  $V_{D_0} = 0.5 \text{ V}$ . [7]
- (b) Validate your assumptions about the states of the diodes. [3]



#### Question 4 [CO2]

**10** 

A voltage waveform  $v_i = 10\sin(100\pi t)$  V is input to a full-wave rectifier with a load resistance of R = 50 k $\Omega$ . Silicon diodes are used in this circuit for which the forward drop is  $V_{D_0} = 0.7$  V.

- (a) Show the circuit of the rectifier. Label the input and output voltages properly. [2]
- (b) Calculate the DC value of the output voltage. [1]
- (c) Contrast the value found in part (b) with that when a 5  $\mu F$  capacitor is connected in parallel with the load.
- (d) **Identify** the two diodes will be ON in the positive half cycle. [1]

Now the two diodes from part (d) are replaced with Germanium diodes  $[V_{D_0} = 0.2 \text{ V}].$ 

Set: 02

#### **BRAC** University

Semster: Spring 2020

Course Title: ELECTRONIC DEVICES AND CIRCLE

Course Title: ELECTRONIC DEVICES AND CIRCUITS Section: 11

Faculty: ABA



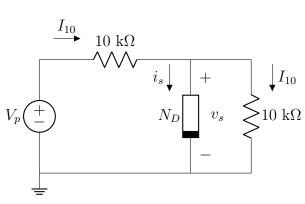
Midterm

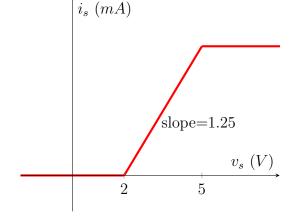
Full Marks: 40

TIme: 2 hours Date: March 10, 2022

### Question 1 [CO1]

10





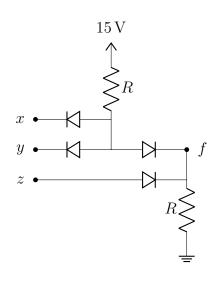
(a) A circuit with a non-linear device  $N_D$ 

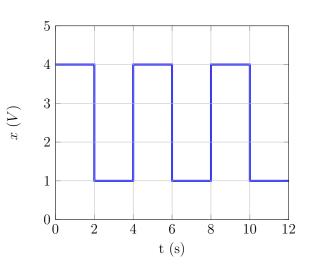
(b) IV Characteristics of the non-linear device  $N_D$ 

- (a) **Identify** the equivalent linear circuit models for the 3 linear segments in the IV characteristics of the non-linear device  $N_D$  and **calculate** the model parameters. [3]
- (b) **Show** the alternative representation of the circuit in Figure (a). [2]
- (c) **Detect** the operating region for the device when  $v_s = 3 \text{ V}$  and **calculate** the current through the device,  $i_s$ , for this voltage. [2]
- (d) **Apply** KVL and KCL to calculate the value of voltage source  $V_p$  when  $v_s = 3$  V. [3]

# Question 2 [CO2]

10





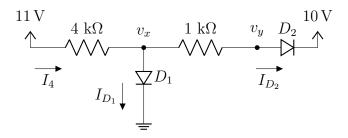
- (a) Assuming x, y, z are boolean variables, **analyze** the circuit on the left to find an expression of f in terms of x, y, and z.
- (b) **Analyze** the circuit on the left again to find the waveform (voltage vs time graph) of f assuming x, y, z are voltage signals, where y = 2 V, z = 3 V, and x has a waveform as shown in the figure on the right.
- (c) **Design** a circuit using ideal diodes to implement the logic function f = x.y.z. Here "." denotes logical AND. [2]

**Bonus: Design** a circuit using ideal diodes to implement the XOR logic function between x and y, assuming you have access to x,  $\bar{x}$ , y, and  $\bar{y}$ .

### Question 3 [CO1]

10

- (a) **Analyze** the following circuit to find the values of  $I_{D_1}$ ,  $I_{D_2}$ ,  $v_x$ , and  $v_y$ . Here, **use** the Method of Assumed State using the CVD model of diode with  $V_{D_0} = 0.5 \text{ V}$ . [7]
- (b) Validate your assumptions about the states of the diodes. [3]



### Question 4 [CO2]

10

A voltage waveform  $v_i = 10\sin(100\pi t)$  V is input to a full-wave rectifier with a load resistance of R = 50 k $\Omega$ . Silicon diodes are used in this circuit for which the forward drop is  $V_{D_0} = 0.7$  V.

- (a) **Show** the circuit of the rectifier. **Label** the input and output voltages properly. [2]
- (b) Calculate the DC value of the output voltage. [1]
- (c) Contrast the value found in part (b) with that when a 5  $\mu F$  capacitor is connected in parallel with the load.
- (d) **Identify** the two diodes will be ON in the positive half cycle. [1]

Now the two diodes from part (d) are replaced with Germanium diodes  $[V_{D_0} = 0.2 \text{ V}].$ 

Set: 03

#### **BRAC** University

Semster: Spring 2020 Course No: CSE251

Course Title: ELECTRONIC DEVICES AND CIRCUITS

Course Title: ELECTRONIC DEVICES AND CIRCUITS Section: 11

Faculty: ABA



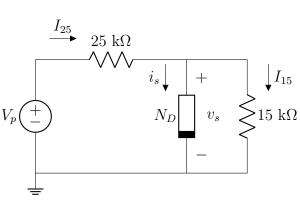
Midterm

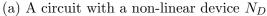
Full Marks: 40

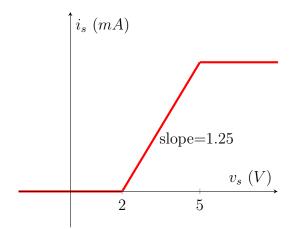
TIme: 2 hours Date: March 10, 2022

### Question 1 [CO1]

**10** 





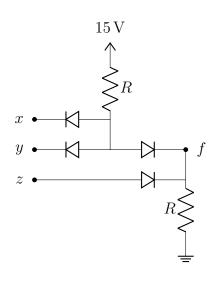


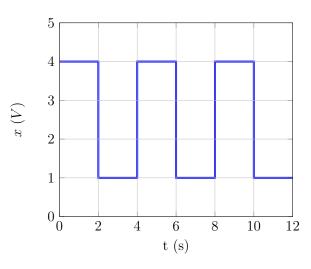
(b) IV Characteristics of the non-linear device  $N_D$ 

- (a) **Identify** the equivalent linear circuit models for the 3 linear segments in the IV characteristics of the non-linear device  $N_D$  and **calculate** the model parameters. [3]
- (b) **Show** the alternative representation of the circuit in Figure (a). [2]
- (c) **Detect** the operating region for the device when  $v_s = 3$  V and **calculate** the current through the device,  $i_s$ , for this voltage. [2]
- (d) **Apply** KVL and KCL to calculate the value of voltage source  $V_p$  when  $v_s = 3$  V. [3]

# Question 2 [CO2]

10





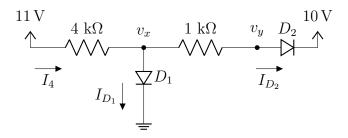
- (a) Assuming x, y, z are boolean variables, **analyze** the circuit on the left to find an expression of f in terms of x, y, and z.
- (b) **Analyze** the circuit on the left again to find the waveform (voltage vs time graph) of f assuming x, y, z are voltage signals, where y = 2 V, z = 3 V, and x has a waveform as shown in the figure on the right.
- (c) **Design** a circuit using ideal diodes to implement the logic function f = x + y + z. Here "+" denotes logical OR. [2]

**Bonus: Design** a circuit using ideal diodes to implement the XOR logic function between x and y, assuming you have access to x,  $\bar{x}$ , y, and  $\bar{y}$ .

### Question 3 [CO1]

10

- (a) **Analyze** the following circuit to find the values of  $I_{D_1}$ ,  $I_{D_2}$ ,  $v_x$ , and  $v_y$ . Here, **use** the Method of Assumed State using the CVD model of diode with  $V_{D_0} = 0.5 \text{ V}$ . [7]
- (b) Validate your assumptions about the states of the diodes. [3]



#### Question 4 [CO2]

10

A voltage waveform  $v_i = 10\sin(100\pi t)$  V is input to a full-wave rectifier with a load resistance of R = 50 k $\Omega$ . Silicon diodes are used in this circuit for which the forward drop is  $V_{D_0} = 0.7$  V.

- (a) **Show** the circuit of the rectifier. **Label** the input and output voltages properly. [2]
- (b) Calculate the DC value of the output voltage. [1]
- (c) Contrast the value found in part (b) with that when a 5  $\mu F$  capacitor is connected in parallel with the load.
- (d) **Identify** the two diodes will be ON in the positive half cycle. [1]

Now the two diodes from part (d) are replaced with Germanium diodes  $[V_{D_0} = 0.2 \text{ V}].$ 

#### **BRAC** University

Set: 04 Semster: Spring 2020

Course No: CSE251 Course Title: ELECTRONIC DEVICES AND CIRCUITS

Section: 11 TIme: 2 hours

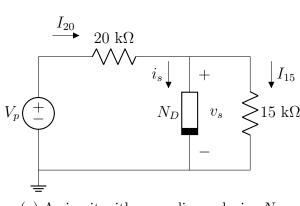
Faculty: ABA Date: March 10, 2022

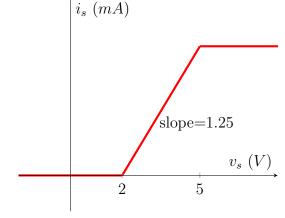
# Question 1 [CO1]

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Midterm

Full Marks: 40

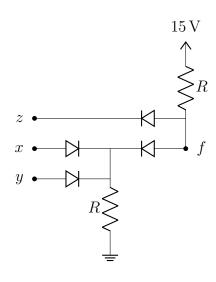


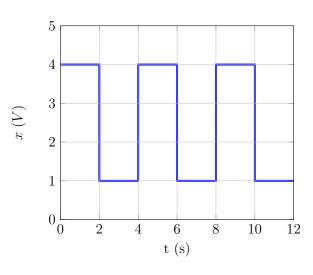


- (a) A circuit with a non-linear device  $N_D$
- (b) IV Characteristics of the non-linear device  $N_D$
- (a) **Identify** the equivalent linear circuit models for the 3 linear segments in the IV characteristics of the non-linear device  $N_D$  and **calculate** the model parameters. [3]
- [2](b) **Show** the alternative representation of the circuit in Figure (a).
- (c) **Detect** the operating region for the device when  $v_s = 3 \text{ V}$  and **calculate** the current through the device,  $i_s$ , for this voltage. [2]
- (d) Apply KVL and KCL to calculate the value of voltage source  $V_p$  when  $v_s = 3$  V. [3]

# Question 2 [CO2]

10





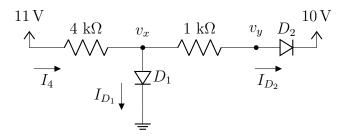
- (a) Assuming x, y, z are boolean variables, **analyze** the circuit on the left to find an expression of f in terms of x, y, and z.
- (b) **Analyze** the circuit on the left again to find the waveform (voltage vs time graph) of f assuming x, y, z are voltage signals, where y = 2 V, z = 3 V, and x has a waveform as shown in the figure on the right.
- (c) **Design** a circuit using ideal diodes to implement the logic function f = x + y + z. Here "+" denotes logical OR. [2]

**Bonus: Design** a circuit using ideal diodes to implement the XOR logic function between x and y, assuming you have access to x,  $\bar{x}$ , y, and  $\bar{y}$ .

### Question 3 [CO1]

10

- (a) **Analyze** the following circuit to find the values of  $I_{D_1}$ ,  $I_{D_2}$ ,  $v_x$ , and  $v_y$ . Here, **use** the Method of Assumed State using the CVD model of diode with  $V_{D_0} = 0.5 \text{ V}$ . [7]
- (b) Validate your assumptions about the states of the diodes. [3]



#### Question 4 [CO2]

10

A voltage waveform  $v_i = 10\sin(100\pi t)$  V is input to a full-wave rectifier with a load resistance of R = 50 k $\Omega$ . Silicon diodes are used in this circuit for which the forward drop is  $V_{D_0} = 0.7$  V.

- (a) **Show** the circuit of the rectifier. **Label** the input and output voltages properly. [2]
- (b) Calculate the DC value of the output voltage. [1]
- (c) Contrast the value found in part (b) with that when a 5  $\mu F$  capacitor is connected in parallel with the load.
- (d) **Identify** the two diodes will be ON in the positive half cycle. [1]

Now the two diodes from part (d) are replaced with Germanium diodes  $[V_{D_0} = 0.2 \text{ V}].$ 

Set: 05

#### **BRAC** University

Semster: Spring 2020

Course No: CSE251

Course Title: FLECTRONIC DEVICES AND CIR

Course Title: ELECTRONIC DEVICES AND CIRCUITS Section: 11

Faculty: ABA



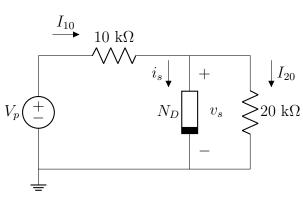
Midterm

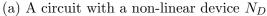
Full Marks: 40 TIme: 2 hours

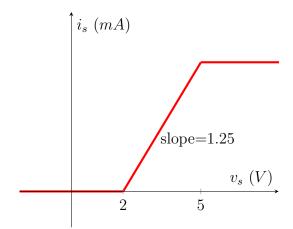
Date: March 10, 2022

# Question 1 [CO1]

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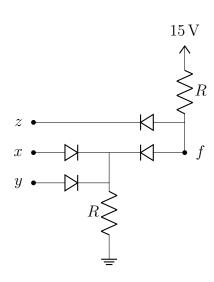


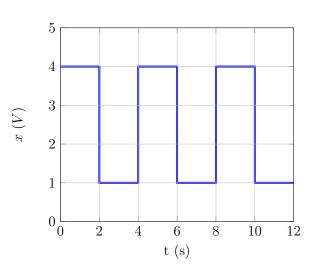
(b) IV Characteristics of the non-linear device  $N_D$ 

- (a) **Identify** the equivalent linear circuit models for the 3 linear segments in the IV characteristics of the non-linear device  $N_D$  and **calculate** the model parameters. [3]
- (b) **Show** the alternative representation of the circuit in Figure (a). [2]
- (c) **Detect** the operating region for the device when  $v_s = 3$  V and **calculate** the current through the device,  $i_s$ , for this voltage. [2]
- (d) **Apply** KVL and KCL to calculate the value of voltage source  $V_p$  when  $v_s = 3$  V. [3]

# Question 2 [CO2]

10





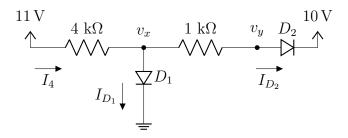
- (a) Assuming x, y, z are boolean variables, **analyze** the circuit on the left to find an expression of f in terms of x, y, and z.
- (b) **Analyze** the circuit on the left again to find the waveform (voltage vs time graph) of f assuming x, y, z are voltage signals, where y = 2 V, z = 3 V, and x has a waveform as shown in the figure on the right.
- (c) **Design** a circuit using ideal diodes to implement the logic function f = x + y + z. Here "+" denotes logical OR. [2]

**Bonus: Design** a circuit using ideal diodes to implement the XOR logic function between x and y, assuming you have access to x,  $\bar{x}$ , y, and  $\bar{y}$ .

### Question 3 [CO1]

10

- (a) **Analyze** the following circuit to find the values of  $I_{D_1}$ ,  $I_{D_2}$ ,  $v_x$ , and  $v_y$ . Here, **use** the Method of Assumed State using the CVD model of diode with  $V_{D_0} = 0.5 \text{ V}$ . [7]
- (b) Validate your assumptions about the states of the diodes. [3]



### Question 4 [CO2]

10

A voltage waveform  $v_i = 10\sin(100\pi t)$  V is input to a full-wave rectifier with a load resistance of R = 50 k $\Omega$ . Silicon diodes are used in this circuit for which the forward drop is  $V_{D_0} = 0.7$  V.

- (a) **Show** the circuit of the rectifier. **Label** the input and output voltages properly. [2]
- (b) Calculate the DC value of the output voltage. [1]
- (c) Contrast the value found in part (b) with that when a 5  $\mu F$  capacitor is connected in parallel with the load.
- (d) **Identify** the two diodes will be ON in the positive half cycle. [1]

Now the two diodes from part (d) are replaced with Germanium diodes  $[V_{D_0} = 0.2 \text{ V}].$ 

Set: 06

#### **BRAC** University

Semster: Spring 2020

Course No: CSE251

Course Title: ELECTRONIC DEVICES AND CIRCUITS

Section: 11
Faculty: ABA



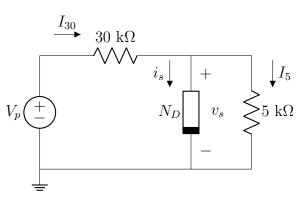
Midterm

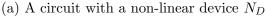
Full Marks: 40

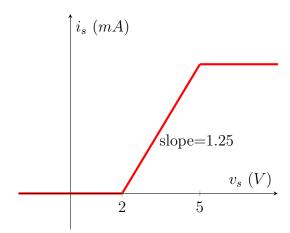
TIme: 2 hours Date: March 10, 2022

### Question 1 [CO1]

**10** 





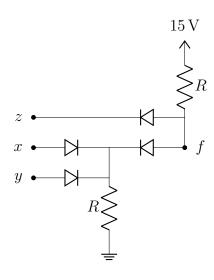


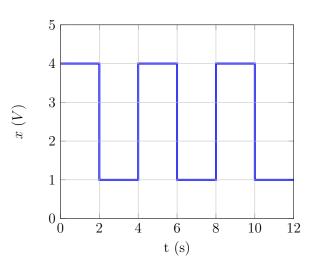
(b) IV Characteristics of the non-linear device  $N_D$ 

- (a) **Identify** the equivalent linear circuit models for the 3 linear segments in the IV characteristics of the non-linear device  $N_D$  and **calculate** the model parameters. [3]
- (b) **Show** the alternative representation of the circuit in Figure (a). [2]
- (c) **Detect** the operating region for the device when  $v_s = 3$  V and **calculate** the current through the device,  $i_s$ , for this voltage. [2]
- (d) **Apply** KVL and KCL to calculate the value of voltage source  $V_p$  when  $v_s = 3$  V. [3]

# Question 2 [CO2]

10





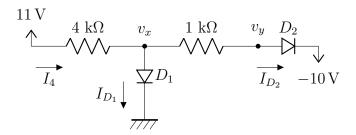
- (a) Assuming x, y, z are boolean variables, **analyze** the circuit on the left to find an expression of f in terms of x, y, and z.
- (b) **Analyze** the circuit on the left again to find the waveform (voltage vs time graph) of f assuming x, y, z are voltage signals, where y = 2 V, z = 3 V, and x has a waveform as shown in the figure on the right.
- (c) **Design** a circuit using ideal diodes to implement the logic function f = x + y + z. Here "+" denotes logical OR. [2]

**Bonus: Design** a circuit using ideal diodes to implement the XOR logic function between x and y, assuming you have access to x,  $\bar{x}$ , y, and  $\bar{y}$ .

### Question 3 [CO1]

10

- (a) **Analyze** the following circuit to find the values of  $I_{D_1}$ ,  $I_{D_2}$ ,  $v_x$ , and  $v_y$ . Here, **use** the Method of Assumed State using the CVD model of diode with  $V_{D_0} = 0.5 \text{ V}$ . [7]
- (b) Validate your assumptions about the states of the diodes. [3]



# Question 4 [CO2]

10

A voltage waveform  $v_i = 10\sin(100\pi t)$  V is input to a full-wave rectifier with a load resistance of R = 50 k $\Omega$ . Silicon diodes are used in this circuit for which the forward drop is  $V_{D_0} = 0.7$  V.

- (a) **Show** the circuit of the rectifier. **Label** the input and output voltages properly. [2]
- (b) Calculate the DC value of the output voltage. [1]
- (c) Contrast the value found in part (b) with that when a 5  $\mu F$  capacitor is connected in parallel with the load.
- (d) **Identify** the two diodes will be ON in the positive half cycle. [1]

Now the two diodes from part (d) are replaced with Germanium diodes  $[V_{D_0} = 0.2 \text{ V}].$ 

Set: 07

#### **BRAC** University

Semster: Spring 2020

Course No: CSE251

Course Title: ELECTRONIC DEVICES AND CIRCUITS

Section: 11
Faculty: ABA



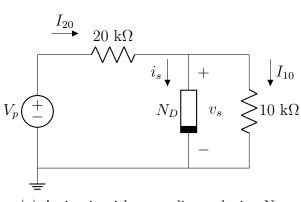
Midterm

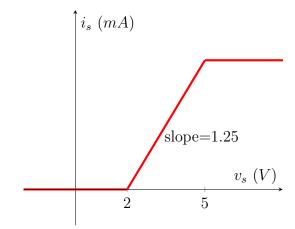
Full Marks: 40 TIme: 2 hours

Date: March 10, 2022

# Question 1 [CO1]

10





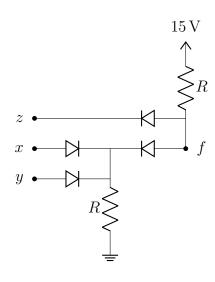
(a) A circuit with a non-linear device  $N_D$ 

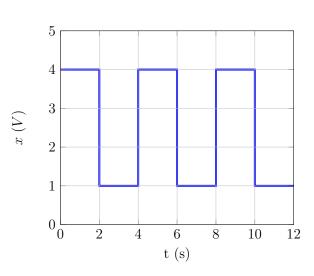
(b) IV Characteristics of the non-linear device  $N_D$ 

- (a) **Identify** the equivalent linear circuit models for the 3 linear segments in the IV characteristics of the non-linear device  $N_D$  and **calculate** the model parameters. [3]
- (b) **Show** the alternative representation of the circuit in Figure (a). [2]
- (c) **Detect** the operating region for the device when  $v_s = 3$  V and **calculate** the current through the device,  $i_s$ , for this voltage. [2]
- (d) **Apply** KVL and KCL to calculate the value of voltage source  $V_p$  when  $v_s = 3$  V. [3]

# Question 2 [CO2]

10





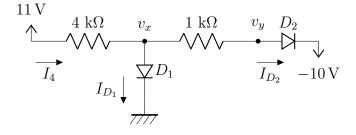
- (a) Assuming x, y, z are boolean variables, **analyze** the circuit on the left to find an expression of f in terms of x, y, and z.
- (b) **Analyze** the circuit on the left again to find the waveform (voltage vs time graph) of f assuming x, y, z are voltage signals, where y = 2 V, z = 3 V, and x has a waveform as shown in the figure on the right. [5]
- (c) **Design** a circuit using ideal diodes to implement the logic function f = x + y + z. Here "+" denotes logical OR. [2]

**Bonus: Design** a circuit using ideal diodes to implement the XOR logic function between x and y, assuming you have access to x,  $\bar{x}$ , y, and  $\bar{y}$ .

### Question 3 [CO1]

10

- (a) **Analyze** the following circuit to find the values of  $I_{D_1}$ ,  $I_{D_2}$ ,  $v_x$ , and  $v_y$ . Here, **use** the Method of Assumed State using the CVD model of diode with  $V_{D_0} = 0.5 \text{ V}$ . [7]
- (b) Validate your assumptions about the states of the diodes. [3]



### Question 4 [CO2]

10

A voltage waveform  $v_i = 10\sin(100\pi t)$  V is input to a full-wave rectifier with a load resistance of R = 50 k $\Omega$ . Silicon diodes are used in this circuit for which the forward drop is  $V_{D_0} = 0.7$  V.

- (a) **Show** the circuit of the rectifier. **Label** the input and output voltages properly. [2]
- (b) Calculate the DC value of the output voltage. [1]
- (c) Contrast the value found in part (b) with that when a 5  $\mu F$  capacitor is connected in parallel with the load.
- (d) **Identify** the two diodes will be ON in the positive half cycle. [1]

Now the two diodes from part (d) are replaced with Germanium diodes  $[V_{D_0} = 0.2 \text{ V}].$ 

Set: 08

#### **BRAC** University

Semster: Spring 2020

Course No: CSE251

Course Title: ELECTRONIC DEVICES AND CIRCUITS

Section: 11
Faculty: ABA



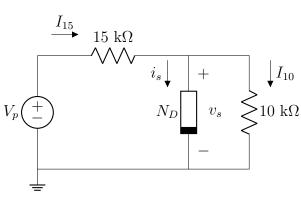
Midterm

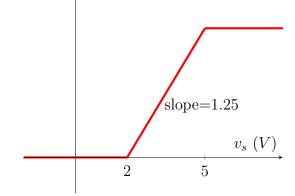
Full Marks: 40 TIme: 2 hours

Date: March 10, 2022

# Question 1 [CO1]

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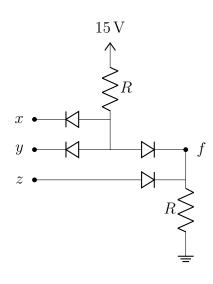


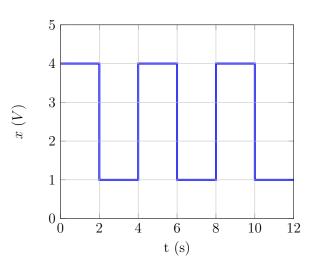
 $i_s (mA)$ 

- (a) A circuit with a non-linear device  $N_D$
- (b) IV Characteristics of the non-linear device  $N_D$
- (a) **Identify** the equivalent linear circuit models for the 3 linear segments in the IV characteristics of the non-linear device  $N_D$  and **calculate** the model parameters. [3]
- (b) **Show** the alternative representation of the circuit in Figure (a). [2]
- (c) **Detect** the operating region for the device when  $v_s = 3$  V and **calculate** the current through the device,  $i_s$ , for this voltage. [2]
- (d) **Apply** KVL and KCL to calculate the value of voltage source  $V_p$  when  $v_s = 3$  V. [3]

# Question 2 [CO2]

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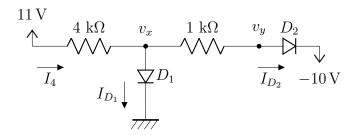
- (a) Assuming x, y, z are boolean variables, **analyze** the circuit on the left to find an expression of f in terms of x, y, and z.
- (b) **Analyze** the circuit on the left again to find the waveform (voltage vs time graph) of f assuming x, y, z are voltage signals, where y = 2 V, z = 3 V, and x has a waveform as shown in the figure on the right.
- (c) **Design** a circuit using ideal diodes to implement the logic function f = x + y + z. Here "+" denotes logical OR. [2]

**Bonus: Design** a circuit using ideal diodes to implement the XOR logic function between x and y, assuming you have access to x,  $\bar{x}$ , y, and  $\bar{y}$ .

### Question 3 [CO1]

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- (a) **Analyze** the following circuit to find the values of  $I_{D_1}$ ,  $I_{D_2}$ ,  $v_x$ , and  $v_y$ . Here, **use** the Method of Assumed State using the CVD model of diode with  $V_{D_0} = 0.5 \text{ V}$ . [7]
- (b) Validate your assumptions about the states of the diodes. [3]



# Question 4 [CO2]

10

A voltage waveform  $v_i = 10\sin(100\pi t)$  V is input to a full-wave rectifier with a load resistance of R = 50 k $\Omega$ . Silicon diodes are used in this circuit for which the forward drop is  $V_{D_0} = 0.7$  V.

- (a) **Show** the circuit of the rectifier. **Label** the input and output voltages properly. [2]
- (b) Calculate the DC value of the output voltage. [1]
- (c) Contrast the value found in part (b) with that when a 5  $\mu F$  capacitor is connected in parallel with the load.
- (d) **Identify** the two diodes will be ON in the positive half cycle. [1]

Now the two diodes from part (d) are replaced with Germanium diodes  $[V_{D_0} = 0.2 \text{ V}].$ 

Set: 09

#### **BRAC** University

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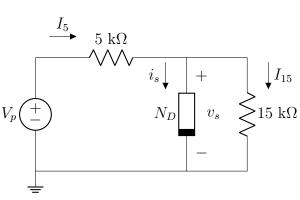
Midterm

Full Marks: 40

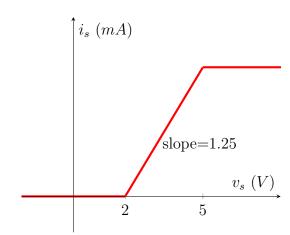
TIme: 2 hours Date: March 10, 2022

### Question 1 [CO1]

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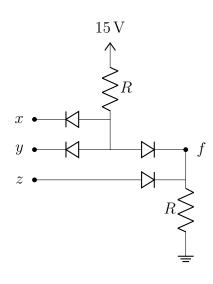


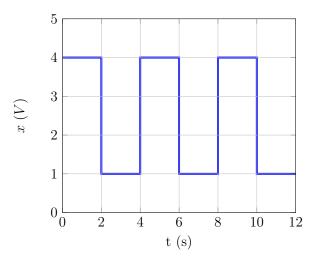
(b) IV Characteristics of the non-linear device  $N_D$ 

- (a) **Identify** the equivalent linear circuit models for the 3 linear segments in the IV characteristics of the non-linear device  $N_D$  and **calculate** the model parameters. [3]
- [2](b) **Show** the alternative representation of the circuit in Figure (a).
- (c) **Detect** the operating region for the device when  $v_s = 3 \text{ V}$  and **calculate** the current through the device,  $i_s$ , for this voltage. [2]
- (d) Apply KVL and KCL to calculate the value of voltage source  $V_p$  when  $v_s = 3$  V. [3]

# Question 2 [CO2]

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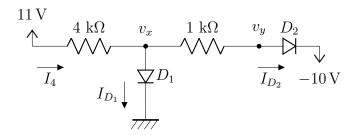
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# Question 4 [CO2]

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A voltage waveform  $v_i = 10\sin(100\pi t)$  V is input to a full-wave rectifier with a load resistance of R = 50 k $\Omega$ . Silicon diodes are used in this circuit for which the forward drop is  $V_{D_0} = 0.7$  V.

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Set: 10

#### **BRAC** University

Semster: Spring 2020 Course No: CSE251

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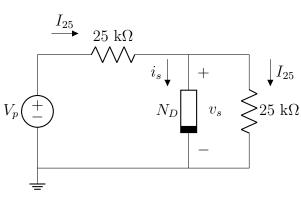
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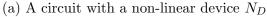
Full Marks: 40

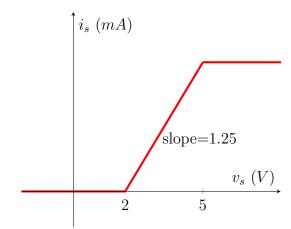
TIme: 2 hours Date: March 10, 2022

### Question 1 [CO1]

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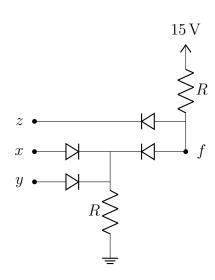


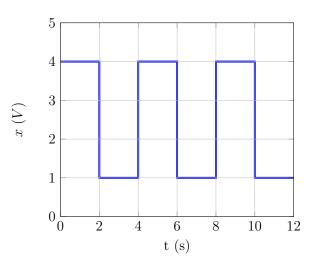


- (b) IV Characteristics of the non-linear device  $N_D$
- (a) **Identify** the equivalent linear circuit models for the 3 linear segments in the IV characteristics of the non-linear device  $N_D$  and **calculate** the model parameters. [3]
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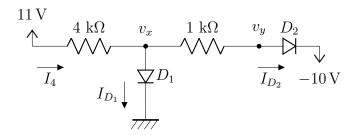
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